

The LA7533 is an IC containing the VIF section and SIF section on a single chip in the DIP20S package. The use of the small-sized package serves to make VTR tuner units smaller.

As compared with the LA7530N, the LA7533 is improved in characteristics when it is operated at supply voltage 9V (DG, DP, RF AGC temperature characteristics).

The LA7533 is applicable to the circuit designed for the LA7530N.

### Functions

- VIF section: VIF AMP, VIDEO DET, PEAK IF AGC, B/W NOISE CANCELLER, RF AGC, AFT, VIDEO MUTE.
- SIF section: SIF LIMITER AMP, FM DET, SND MUTE.

### Features

- High-gain VIF amp requiring no preamp.
- Higher AGC speed.
- Adjustment-free FM detector because of ceramic discriminator-used quadrature detection.
- Possible to mute video, sound for VTR.
- Small-sized package.
- Minimum number of external parts required.
- Operated at supply voltage 9V

### Maximum Ratings at Ta = 25°C

			unit
Maximum Supply Voltage	V <sub>CC</sub> max	14	V
External Flow-out Current	I <sub>16</sub> max	5	mA
Pin 20 Maximum Supply Voltage	V <sub>20</sub> max	V <sub>CC</sub>	V
Allowable Power Dissipation	P <sub>d</sub> max	Ta ≤ 40°C	1.1 W
Operating Temperature	T <sub>opr</sub>	-20 to +70	°C
Storage Temperature	T <sub>stg</sub>	-55 to +125	°C

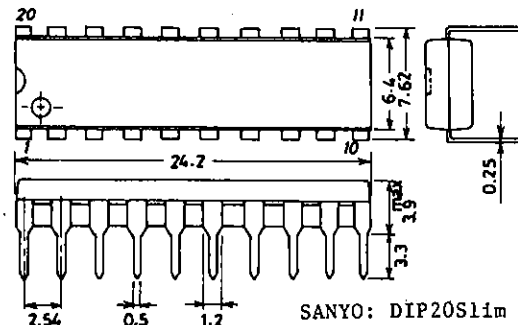
### Operating Conditions at Ta = 25°C

			unit
Recommended Supply Voltage	V <sub>CC</sub>	9	V
Operating Voltage Range	V <sub>CC</sub> op	8.1 to 13.2	V

### Package Dimensions

(unit : mm)

3021B

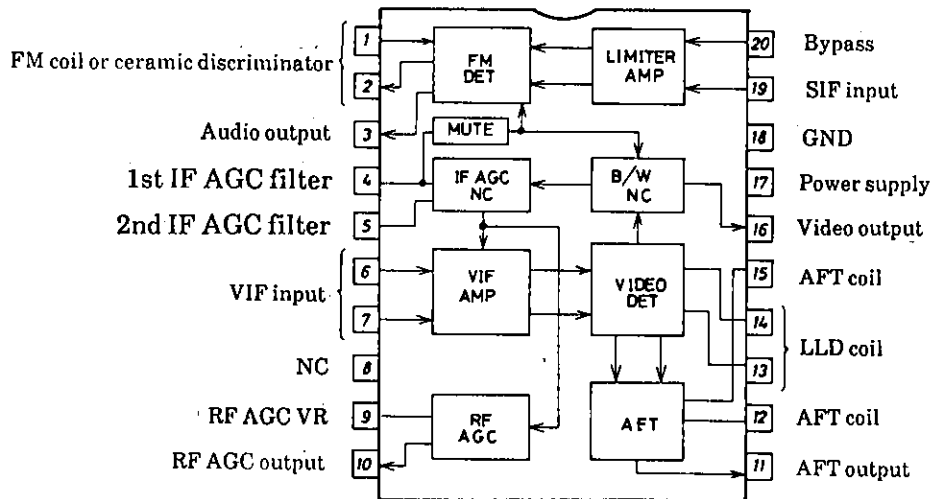


LA7533

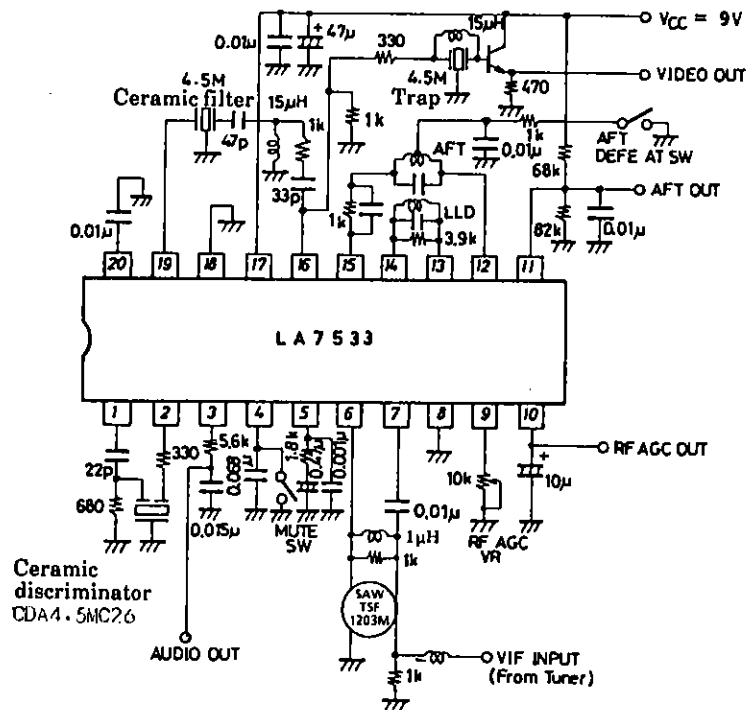
Operating Characteristics at  $T_a = 25^\circ\text{C}$ ,  $V_{CC} = 9\text{V}$ ,  $f_p = 58.75\text{MHz}$ ,  $f_s = 54.25\text{MHz}$  (VIF),  
 $f_o = 4.5\text{MHz}$  (SIF)

			min	typ	max	unit
Total Circuit Current	$I_{17}$	DC	40	49	63	mA
Maximum RF AGC Voltage	$V_{10H}$	DC	6.2	6.5	6.8	V
Minimum RF AGC Voltage	$V_{10L}$	DC		0.1	0.5	V
Quiescent Video	$V_{16}$	DC	4.2	4.6	5.0	V
Output Voltage						
Quiescent AFT Output Voltage	$V_{11}$	DC	2.9	4.9	5.9	V
Input Sensitivity	$V_i$	$f_m = 400\text{Hz}$ 40%AM, $V_o = 0.8\text{Vp-p}$	31	37	42	dB $\mu$
AGC Range	GR	$f_m = 400\text{Hz}$ 40%AM, $V_o = 0.8\text{Vp-p}$	57	63		dB
Maximum Allowable Input	$V_i \text{ max}$	$f_m = 15\text{kHz}$ 78%AM, $V_o = \pm 1\text{dB}$	90	130		mVrms
Video Output Amplitude	$V_o(\text{VIDEO})$	$V_i = 10\text{mVrms}$ , $f_m = 15\text{kHz}$ 78%AM	1.4	1.65	1.9	Vp-p
Output S/N	S/N	$V_i = 10\text{mVrms}$ CW	48	53		dB
Carrier Leak	CL	$V_i = 100\text{mVrms}$ , $f_m = 15\text{kHz}$ 78%AM	50	55		dB
Maximum AFT Voltage	$V_{11H}$	$V_i = 10\text{mVrms}$ SWEEP	8.1	8.5	8.9	V
Minimum AFT Voltage	$V_{11L}$	$V_i = 10\text{mVrms}$ SWEEP	0.1	0.4	0.9	V
AFT Detection Sensitivity	$S_f$	$V_i = 10\text{mVrms}$ SWEEP	45	70	90	mV/kHz
White Noise Threshold Level	$V_{WTH}$	$V_i = 10\text{mVrms}$ SWEEP	4.7	5.1	5.5	V
White Noise Clamp Level	$V_{WCL}$	$V_i = 10\text{mVrms}$ SWEEP	2.9	3.3	3.7	V
Black Noise Threshold Level	$V_{BTH}$	$V_i = 10\text{mVrms}$ SWEEP	1.6	1.85	2.1	V
Black Noise Clamp Level	$V_{BCL}$	$V_i = 10\text{mVrms}$ SWEEP	2.6	2.9	3.2	V
SIF Output Signal Voltage	$V_o(\text{SIF})$	P/S = 20dB	70	100	140	mVrms
Frequency Characteristic	$f_c$	-3dB	5	7		MHz
Differential Gain	DG	$V_i = -27\text{dBm}$ (peak) 87.5% VIDEOMOD		3		%
Differential Phase	DP	$V_i = -27\text{dBm}$ (peak) 87.5% VIDEOMOD		3		deg
VIF Input Resistance	$r_i$			1.5		k $\Omega$
VIF Input Capacitance	$c_i$			3.0		pF
SIF Limiting Voltage	$V_i(\text{lim})$	-3dB	300	600		$\mu\text{Vrms}$
Detection Output Voltage	$V_o(\text{DET})$	$V_i = 100\text{mVrms}$ , $f_m = 400\text{Hz}$ , $\Delta f = \pm 25\text{kHz}$	440	670	800	mVrms
Total Harmonic Distortion	THD (DET)	$V_i = 100\text{mVrms}$ , $f_m = 400\text{Hz}$ , $\Delta f = \pm 25\text{kHz}$		0.6	1.5	%
AM Rejection	AMR	$V_i = 100\text{mVrms}$ , $f_m = 400\text{Hz}$ , $\Delta f = \pm 25\text{kHz}$ 30%AM	50	60		dB
Noise Output Voltage	$V_N$				3.5	mVrms
Pin 4 Muting Start Voltage	$V_{M(4)}$		0.3	0.5		V
Pin 20 Muting Attenuation	$ATT_{M(20)}$		60			dB

Equivalent Circuit Block Diagram



## Sample Application Circuit (USA)



Unit (resistance:Ω, capacitance:F)

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